

RB520CS30L

100 mA low V_F MEGA Schottky barrier rectifier Rev. 1 — 10 March 2011

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD882 leadless ultra small Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

Average forward current: I_{F(AV)} ≤ 100 mA

Reverse voltage: V_R ≤ 30 V

Low forward voltage: V_F ≤ 450 mV

■ Low reverse current: $I_R \le 0.5 \mu A$

AEC-Q101 qualified

Leadless ultra small SMD plastic package

1.3 Applications

- Low current rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{F(AV)}$	average forward current	square wave; δ = 0.5; f = 20 kHz				
		T _{amb} ≤ 135 °C	<u>[1]</u> _	-	100	mA
		T _{sp} ≤ 145 °C	-	-	100	mA
I _R	reverse current	V _R = 10 V	-	0.14	0.5	μΑ
V_R	reverse voltage		-	-	30	V
V _F	forward voltage	I _F = 10 mA	[2] _	330	450	mV

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm².



^[2] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

100 mA low V_F MEGA Schottky barrier rectifier

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	. 54
2	anode	1 2	1 2 sym001
		Transparent top view	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package	Package		
	Name	Description	Version	
RB520CS30L	-	leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm	SOD882	

4. Marking

Table 4. Marking codes

Type number	Marking code
RB520CS30L	AP

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	30	V
I _{F(AV)}	average forward current	square wave; δ = 0.5; f = 20 kHz			
		T _{amb} ≤ 135 °C	<u>[1]</u> -	100	mA
		T _{sp} ≤ 145 °C	-	100	mA
I _{FSM}	non-repetitive peak forward current	$\begin{array}{l} \text{half sine wave;} \\ t_p \leq 8.3 \text{ ms} \end{array}$	[2] -	3	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[4][3]	315	mW
			[4][1]	565	mW
			[4][5]	865	mW

100 mA low V_F MEGA Schottky barrier rectifier

Table 5. Limiting values ... continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [2] $T_i = 25$ °C prior to surge.
- 3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [4] Reflow soldering is the only recommended soldering method.
- [5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

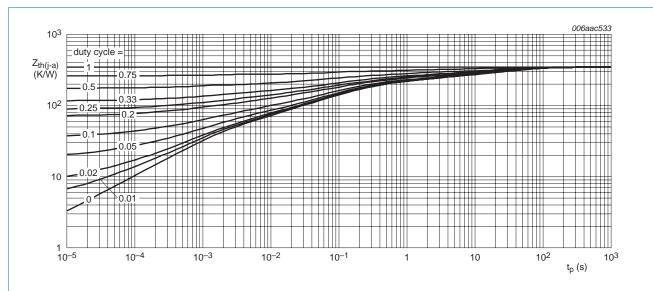
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	[1][2]				
		[3]	-	-	395	K/W	
			<u>[4]</u>	-	-	220	K/W
			<u>[5]</u>	-	-	145	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		<u>[6]</u>	-	-	70	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- 6] Soldering point of cathode tab.

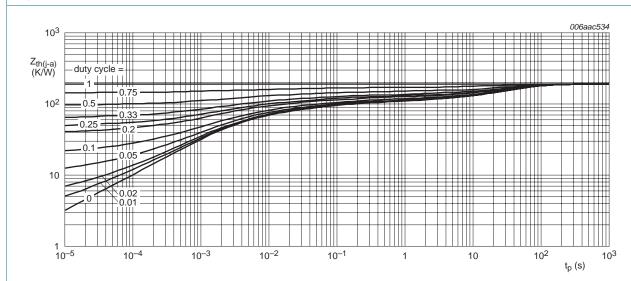
RB520CS30L

100 mA low V_F MEGA Schottky barrier rectifier



FR4 PCB, standard footprint

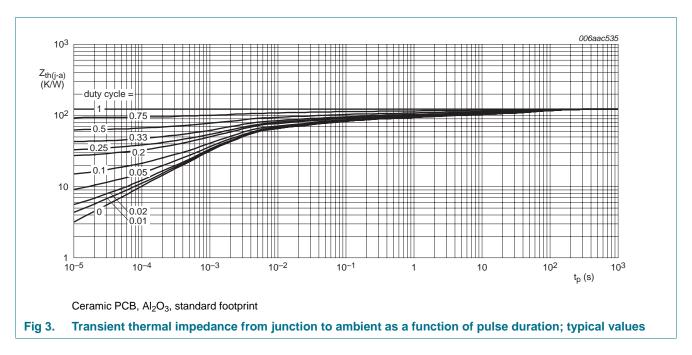
Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm²

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

100 mA low V_F MEGA Schottky barrier rectifier



7. Characteristics

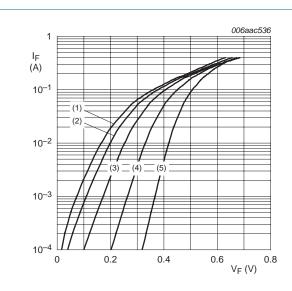
Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage		<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	210	-	mV
		I _F = 1 mA	-	270	-	mV
		I _F = 10 mA	-	330	450	mV
		$I_F = 100 \text{ mA}$	-	450	-	mV
I _R	reverse current	V _R = 10 V	-	0.14	0.5	μΑ
C_d	diode capacitance	$V_R = 1 V$; $f = 1 MHz$	-	10	-	pF

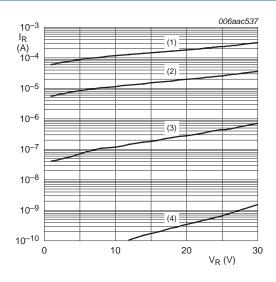
^[1] Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

100 mA low V_F MEGA Schottky barrier rectifier



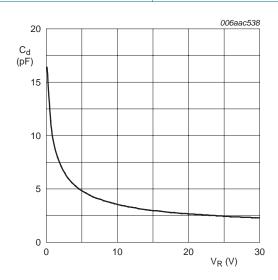
- (1) $T_i = 150 \,^{\circ}\text{C}$
- (2) $T_i = 125 \, ^{\circ}\text{C}$
- (3) $T_i = 85 \, ^{\circ}\text{C}$
- (4) $T_j = 25 \,{}^{\circ}\text{C}$
- (5) $T_i = -40 \, ^{\circ}C$

Fig 4. Forward current as a function of forward voltage; typical values



- (1) $T_j = 125 \, ^{\circ}C$
- (2) $T_j = 85 \, ^{\circ}C$
- (3) $T_j = 25 \, ^{\circ}C$
- (4) $T_j = -40 \, ^{\circ}C$

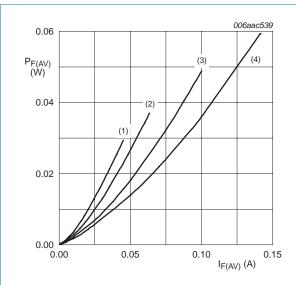
Fig 5. Reverse current as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

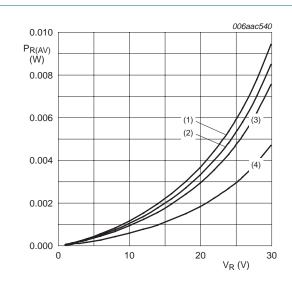
Fig 6. Diode capacitance as a function of reverse voltage; typical values

100 mA low V_F MEGA Schottky barrier rectifier



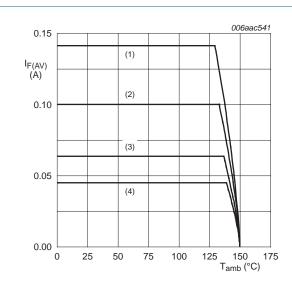
- (1) $\delta = 0.1$
- (2) $\delta = 0.2$
- (3) $\delta = 0.5$
- (4) $\delta = 1$

Fig 7. Average forward power dissipation as a function of average forward current; typical values



- (1) $\delta = 1$; DC
- (2) $\delta = 0.9$; f = 20 kHz
- (3) $\delta = 0.8$; f = 20 kHz
- (4) $\delta = 0.5$; f = 20 kHz

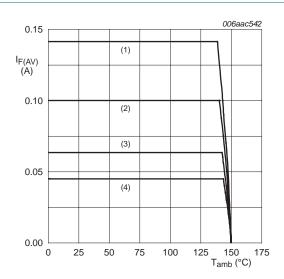
Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 9. Average forward current as a function of ambient temperature; typical values

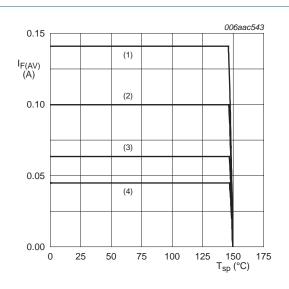


FR4 PCB, mounting pad for cathode 1 cm²

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 10. Average forward current as a function of ambient temperature; typical values

100 mA low V_F MEGA Schottky barrier rectifier

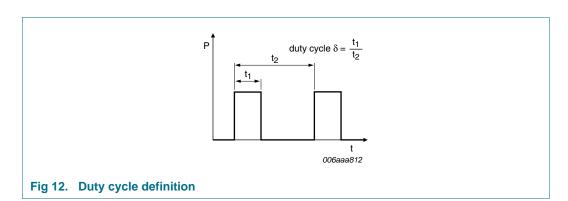


T_i = 150 °C

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 11. Average forward current as a function of solder point temperature; typical values

8. Test information



The current ratings for the typical waveforms as shown in Figure 9, 10 and 11 are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current,

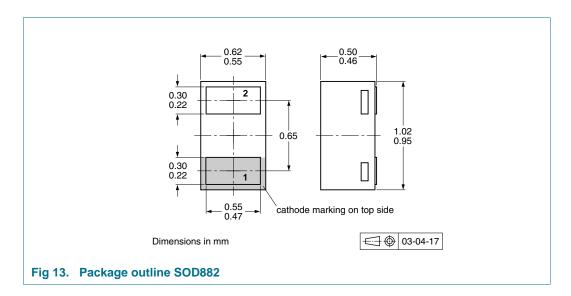
 $I_{RMS}=I_{F(AV)}$ at DC, and $I_{RMS}=I_{M}\times\sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

100 mA low V_F MEGA Schottky barrier rectifier

9. Package outline



10. Packing information

Table 8. Packing methods

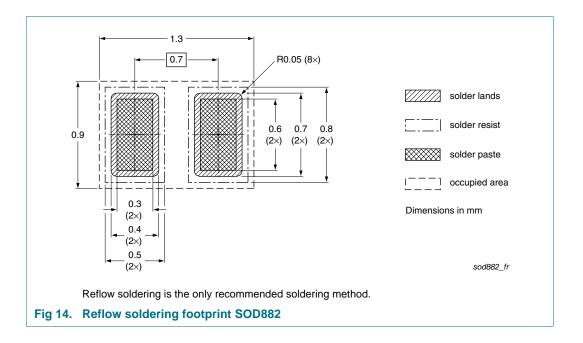
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity 10 000
RB520CS30L	SOD882	2 mm pitch, 8 mm tape and reel	-315

^[1] For further information and the availability of packing methods, see $\underline{\text{Section 14}}$.

100 mA low V_F MEGA Schottky barrier rectifier

11. Soldering



100 mA low V_F MEGA Schottky barrier rectifier

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
RB520CS30L v.1	20110310	Product data sheet	-	-

11 of 14

100 mA low V_F MEGA Schottky barrier rectifier

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or

malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

RB520CS30L

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2011. All rights reserved.

100 mA low V_F MEGA Schottky barrier rectifier

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

RB520CS30L

100 mA low V_F MEGA Schottky barrier rectifier

15. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 2
6	Thermal characteristics 3
7	Characteristics 5
8	Test information 8
8.1	Quality information 8
9	Package outline 9
10	Packing information 9
11	Soldering 10
12	Revision history 11
13	Legal information 12
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks
14	Contact information
15	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.